TOSHIBA Diode Silicon Epitaxial Schottky Barrier Type

HN2S01F

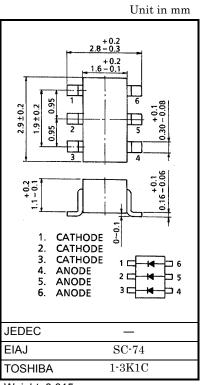
Low Voltage High Speed Switching Application

- HN2S01F is composed of 3 independent diodes.
- Low reverse current: $V_F = 0.23V$ (typ.) @ $I_F = 5mA$

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Maximum (peak) reverse Voltage	V_{RM}	15	V
Reverse voltage	V _R	10	V
Maximum (peak) forward current	I _{FM}	200 *	mA
Average forward current	Io	100 *	mA
Surge current (10ms)	I _{FSM}	1 *	Α
Power dissipation	Р	300	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C
Operating temperature range	T _{opr}	-40~100	°C

^{* :} This is maximum rating of single diode (Q1 or Q2 or Q3). In the case of using 2 ro 3 diodes, the maximum ratings per diodes is 75 % of the single diode one.



Weight: 0.015g

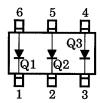
Electrical Characteristics (Q1, Q2, Q3 Common, Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Forward voltage	V _{F (1)}	_	I _F = 1mA	_	0.18	_	
	V _{F (2)}	_	I _F = 5mA	_	0.23	0.30	V
	V _{F (3)}	_	I _F = 100mA		0.35	0.50	
Reverse current	I _R	_	V _R = 10V		_	20	μΑ
Total capacitance	C _T	_	V _R = 0, f = 1MH _z	_	20	40	рF

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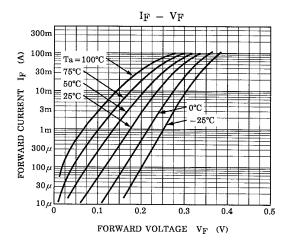
Pin Assignment (Top View)

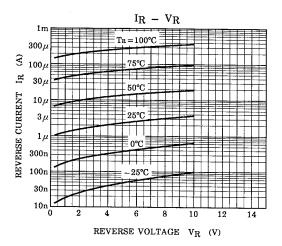
Marking

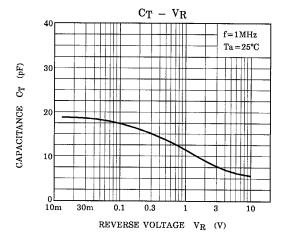


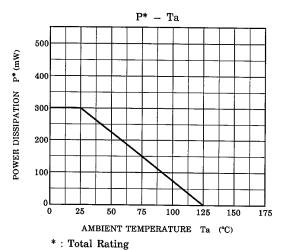


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